

### **Features**

- AEC-Q101 Qualified
- Trench FET Power MOSFET
- Halogen Free (Note1)
- Moisture Sensitivity Level 3
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

# **N-Channel MOSFET**

## **Maximum Ratings**

• Operating Junction Temperature Range : -55°C to +150°C

• Storage Temperature Range: -55°C to +150°C

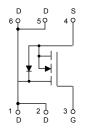
• Thermal Resistance: 167°C/W Junction to Ambient (Note2)

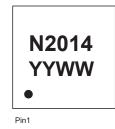
Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V <sub>DS</sub>	12	V
Gate-Source Volltage	V <sub>GS</sub>	±8	V
Continuous Drain Current	I <sub>D</sub>	15	Α
Pulsed Drain Current (Note3)	I <sub>DM</sub>	60	Α
Single Pulsed Avalanche Energy <sub>(L=0.5mH)</sub>	E <sub>AS</sub>	25	mJ

#### Notes:

- 1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 2. Surface Mounted On FR4 Board Using The Minimum Pad Size,1oz Copper.
- 3. Surface Mounted On FR4 Board Using 1 Square Inch Pad Size, 1oz Copper.

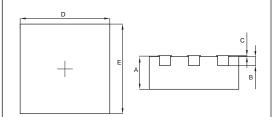
# **Internal Structure and Marking Code**

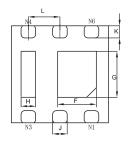




YYWW: 4 codes in total YY is the year WW is the cycle

## DFN2020-6LE





	DIMENSIONS					
DIM	INCHES		MM		NOTE	
	MIN	MAX	MIN	MAX	NOTE	
Α	0.030	0.033	0.750	0.850		
В	0.008		0.200		REF.	
С	0.000	0.002	0.000	0.050		
D	0.075	0.083	1.900	2.100		
Е	0.075	0.083	1.900	2.100		
F	0.024	0.031	0.610	0.810		
G	0.028	0.036	0.710	0.910		
Н	0.008	0.016	0.200	0.400		
J	0.010	0.014	0.250	0.350		
K	0.008	0.012	0.200	0.300		
L	0.026		0.650		TYP.	



# ELECTRICAL CHARACTERISTICS (Ta=25°C unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Тур	Max	Unit	
Static Characteristics			1				
Drain-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =250μA	12			V	
Gate-Threshold Voltage <sup>(Note 4)</sup>	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250μA	0.40	0.7	1.1	V	
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =± 8V, V <sub>DS</sub> =0V			±100	nA	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =12V, V <sub>GS</sub> =0V			1	μA	
		V <sub>GS</sub> =8V, I <sub>D</sub> =5A		5	8	mΩ	
Drain-Source On-Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =4.5V, I <sub>D</sub> =5A		7	9		
		V <sub>GS</sub> =2.5V, I <sub>D</sub> =5A		9	11		
Forward Transconductance (Note 4)	<b>g</b> FS	V <sub>DS</sub> =6V, I <sub>D</sub> =5A		40		S	
Diode Forward Voltage	V <sub>SD</sub>	V <sub>GS</sub> =0V, I <sub>S</sub> =10A			1.2	٧	
Dynamic Characteristics (Note 5	5)						
Input Capacitance	C <sub>iss</sub>			1791		pF	
Output Capacitance	C <sub>oss</sub>	V <sub>DS</sub> =10V,V <sub>GS</sub> =0V, f=1MHz		229			
Reverse Transfer Capacitance	C <sub>rss</sub>			197			
Gate Resistance	$R_g$	f=1MHz		11		Ω	
Switching Characteristics <sup>(Note</sup>	5)		-				
Turn-On Delay Time	$t_{d(on)}$			6.5			
Turn-On Rise Time	t <sub>r</sub>	V <sub>DD</sub> =10V,V <sub>GEN</sub> =8V,		42			
Turn-Off Delay Time	t <sub>d(off)</sub>	$I_D$ =10A, $R_G$ =4.5 $\Omega$ , $R_L$ =1 $\Omega$		56		ns	
Turn-Off Fall Time	t <sub>f</sub>			32			
Total Gate Charge	Qg			48			
Gate-Source Chage	Q <sub>gs</sub>	V <sub>DS</sub> =10V,Vgs=8V,I <sub>D</sub> =10A		5.2		nC	
Gage-Drain Charge	$Q_{gd}$			4.6			

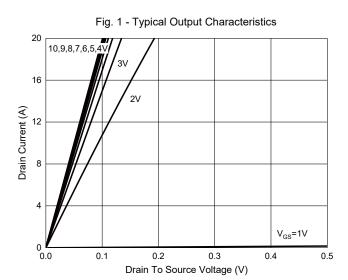
#### Notes

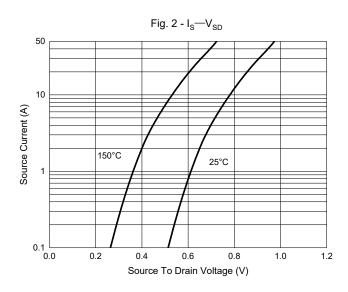
<sup>4.</sup> Pulse Test: Pulse Width≤300μs,Duty Cycle≤2%.

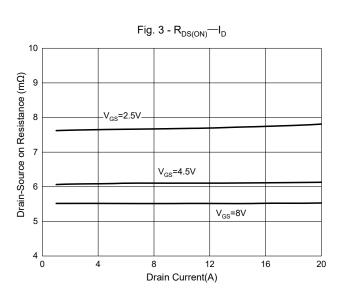
<sup>5.</sup> These Parameters Have No Way To Verify.

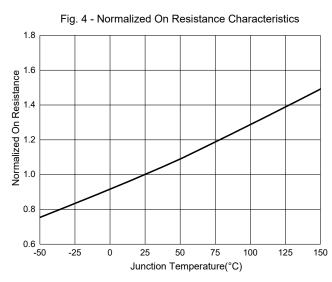


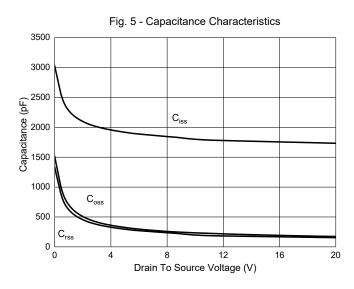
## **Curve Characteristics**

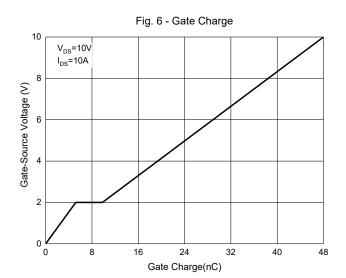






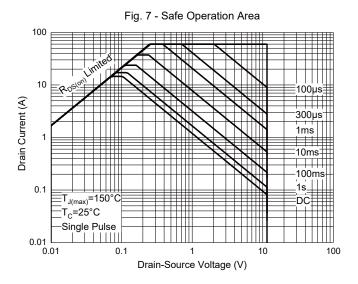








# **Curve Characteristics**





### **Ordering Information**

Device	Packing
Part Number-TP	Tape&Reel:3Kpcs/Reel

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